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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/767,281	01/30/2004	Tae-Sung Kim	P57002	4288
75	90 07/28/2006		EXAMINER	
Robert E. Bushnell			WARREN, MATTHEW E	
Suite 300 1522 K Street, N.W.			ART UNIT	PAPER NUMBER
Washington, DC 20005			2815	
			DATE MAILED: 07/28/2006	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/767,281	KIM ET AL.			
Office Action Summary	Examiner	Art Unit			
	Matthew E. Warren	2815			
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address			
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim vill apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONED	l. ely filed the mailing date of this communication. O (35 U.S.C. § 133).			
Status					
1)⊠ Responsive to communication(s) filed on <u>15 May 2006</u> . (a)□ This action is FINAL . 2b)⊠ This action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims					
4) ☐ Claim(s) 1,2,4-9,11-15,17-19 and 21-24 is/are 4a) Of the above claim(s) is/are withdraw 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1, 2, 4-9, 11-15, 17-19, and 21-24 is/a 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or	vn from consideration. are rejected. r election requirement.				
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) acce Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex	epted or b) objected to by the Eddrawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	ected to. See 37 CFR 1.121(d).			
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the prior application from the International Bureau * See the attached detailed Office action for a list	s have been received. s have been received in Application rity documents have been receive u (PCT Rule 17.2(a)).	on No d in this National Stage			
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal Pa				

DETAILED ACTION

This Office Action is in response to the Amendment filed on May 15, 2006.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1, 2, 4-9, 11-15, 17-19, and 21-24 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ohtani et al. (US 6,271,543 B1) in view of Maeda (US 5,278,099).

In re claims 1 and 14, Ohtani shows (figs. 2A-3A and col. 6, line 38 – col. 7, line 22) a thin film transistor (208), comprising a source electrode (206), a drain electrode (207), a gate electrode (202) and a semiconductor layer (201), wherein one of the source electrode and the drain electrode comprises an aluminum layer disposed between a pair of titanium layers (col. 7, lines 10-13). Ohtani shows all of the elements of the claims except the aluminum layer being an aluminum alloy and a diffusion prevention layer interposed between the aluminum alloy layer and each of the pair of titanium layers. Maeda shows (fig. 1F) a source/drain electrode having a titanium layer (32), an aluminum alloy layer (36) (col. 4, lines 22-31), and a titanium nitride layer (34) interposed between the Ti and Al alloy to act as a barrier for blocking Al diffusion and preventing the growth of alloy spikes (col. 3, lines 46-61). The aluminum layer may be

alloyed with Si to reduce the resistance and prevent openings in the wiring (col. 4, lines 22-31). Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the Ti/Al/Ti source/drain electrode of Ohtani by alloying Si with aluminum and forming TiN between the Ti and Al alloy layers as taught by Maeda to reduce resistance of the contact and prevent Al diffusion and the growth of alloy spikes.

In re claims 2 and 15, Maeda discloses (col. 4, lines 22-31) that the aluminum alloy layer comprises an element selected from a group consisting of silicon, copper, neodymium, platinum and nickel. Maeda does not disclose the specific weight percentage of the element in the alloy. However, It would have been obvious to one of ordinary skill in the art at the time the invention was made to form the aluminum alloy having the desired percentage of an element, since it has been held that discovering an optimum value of a result effective variable involves only routine skill in the art. In re Boesch, 617 F.2d 272, 205 USPQ 215 (CCPA 1980).

In re claim 4, Maeda discloses (col. 3, lines 46-61) each diffusion prevention layer is made of titanium nitride.

In re claims 5 and 6, the references do not teach the thickness of the titanium nitride or the percentage of nitrogen in the TiN being within the desired range. However, it would have been obvious to one of ordinary skill in the art to make the thickness of the TiN layer or the percentage of nitrogen within the desired range, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering

Application/Control Number: 10/767,281

Art Unit: 2815

the optimum or workable ranges involves only routine skill in the art. *In re Aller, 105 USPQ 233.*

In re claims 7 and 19, Maeda discloses (col. 4, lines 22-31) that the Al electrode is an alloy containing Si and is therefore absent of pure aluminum.

In re claims 17 and 18, a "product by process" claim limitation is directed to the product per se, no matter how actually made, In re Hirao, 190 USPQ 15 at 17(footnote 3). See also in re Brown, 173 USPQ 685: In re Luck, 177 USPQ 523; In re Fessmann, 180 USPQ 324: In re Avery, 186 USPQ 116 in re Wertheim, 191 USPQ 90 (209 USPQ 254 does not deal with this issue); and In re Marosi et al, 218 USPQ 289 final product per se which must be determined in a "product by, all of" claim, and not the patentability of the process, and that an old or obvious product, whether claimed in "product by process" claims or not. Note that Applicant has the burden of proof in such cases, as the above case law makes clear. "Even though product-by- process claims are limited by and defined by the process, determination of patentability is based upon the product itself. The patentability of a product does not depend on its method of production. If the product in product-by-process claim is the same as or obvious from a product of the prior art, the claim is unpatentable even though the prior product is made by a different process." In re Thorpe, 227 USPQ 964, 966 (Fed. Cir. 1985)(citations omitted).

In re claims 8 and 21, Ohtani shows (figs. 2A-3A) a flat panel display and a process for making a flat panel display(col. 6, line 38 – col. 7, line 26) comprising forming: a substrate; a first plurality of thin film transistors formed on a surface of the

substrate (there is a plurality of TFT's because the invention pertains to an active matrix array-which is known to contain many devices), the first plurality of thin film transistors comprising first source electrodes (connected 206), first drain electrodes (207), first gate electrodes (connected 202), and semiconductor layers (201); a plurality of first conductive lines (source wiring lines) electrically connected to the first source electrodes; and a plurality of second conductive lines (gate wiring lines) electrically connected to the first gate electrodes. Although Ohtani does not show the complete active matrix having a second plurality of thin film transistors, wherein the first drain electrodes of the first plurality of thin film transistors are electrically connected to gate electrodes of the second plurality of thin film transistors, such a recitation is of a well known routing scheme. (For instance Yamazaki et al. US Pub. 20003/0222575 A1 discloses [0175] a complete device having the gate electrode of one TFT connected to a drain electrode of another TFT for a driving circuit.). One of the first source electrodes, the first drain electrodes, the plurality of first conductive lines, and the plurality of second conductive lines comprises an aluminum layer disposed between a pair of titanium layers (col. 7, lines 10-13). Ohtani shows all of the elements of the claims except the alloy layer being an aluminum alloy and a diffusion prevention layer interposed between the aluminum alloy layer and each of the pair of titanium layers. Maeda shows (fig. 1F) a source/drain electrode having a titanium layer (32), an aluminum alloy layer (36) (col. 4, lines 22-31), and a titanium nitride layer (34) interposed between the Ti and Al alloy to act as a barrier for blocking Al diffusion and preventing the growth of alloy spikes (col. 3, lines 46-61). The aluminum layer may be

Art Unit: 2815

alloyed with Si to reduce the resistance and prevent openings in the wiring (col. 4, lines 22-31). Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the Ti/Al/Ti source/drain electrode of Ohtani by alloying Si with aluminum and forming TiN between the Ti and Al alloy layers as taught by Maeda to reduce resistance of the contact and prevent Al diffusion and the growth of alloy spikes.

In re claims 9 and 22,, Maeda discloses (col. 4, lines 22-31) that the aluminum alloy layer comprises an element selected from a group consisting of silicon, copper, neodymium, platinum and nickel. Maeda does not disclose the specific weight percentage of the element in the alloy. However, It would have been obvious to one of ordinary skill in the art at the time the invention was made to form the aluminum alloy having the desired percentage of an element, since it has been held that discovering an optimum value of a result effective variable involves only routine skill in the art. In re-Boesch, 617 F.2d 272, 205 USPQ 215 (CCPA 1980).

In re claims 11 and 23, Maeda discloses (col. 3, lines 46-61) each diffusion prevention layer is made of titanium nitride.

In re claims 12 and 24, the references do not teach the thickness of the titanium nitride or the percentage of nitrogen in the TiN being within the desired range. However, it would have been obvious to one of ordinary skill in the art to make the thickness of the TiN layer or the percentage of nitrogen within the desired range, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering

the optimum or workable ranges involves only routine skill in the art. *In re Aller, 105 USPQ 233.*

Response to Arguments

Applicant's arguments filed with respect to claims 1, 2, 4-9, 11-15, 17-19, and 21-24 have been fully considered but they are not persuasive. The applicant primarily asserts that the prior art references do not show all of the elements of the claims, specifically citing that Ohtani only discloses Ti/Al/Ti structure and does not disclose an aluminum alloy layer. The examiner believes that the prior art references show all of the elements of the claims and that the combined references show all of the elements of the claims. As stated in the rejection above, Ohtani discloses that the source and drain electrodes have a Ti/Al/Ti structure, but does not specifically disclose that the Al layer is an aluminum alloy layer. The gate electrode having the same Ti/Al/Ti structure is cited in Ohtani as using an Al alloy layer. Therefore, it is assumed that the source and drain electrodes of Ohtani may also comprise an Al alloy. However, Maeda was cited in part to cure the deficiencies of Ohtani in that respect and disclose that an electrode can comprise an alloy of aluminum. Maeda specifically disclosed in column 4, lines 22-31 that aluminum can be alloyed with si to reduce the resistance of the layer. Therefore, Maeda cures the deficiencies of Ohtani and the combined references show all of the elements of the claims.

Application/Control Number: 10/767,281 Page 8

Art Unit: 2815

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Fujikawa (US 6,414,738 B1) and Hirano et al. (US Pub. 2001/0020702 A1) also show devices having source and drain electrodes with a laminated structure.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Matthew E. Warren whose telephone number is (571) 272-1737. The examiner can normally be reached on Mon-Thur and alternating Fri 9:00-5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Kenneth Parker can be reached on (571) 272-2298. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Application/Control Number: 10/767,281

Art Unit: 2815

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Page 9

Matthew E. Warren

Mutter me

July 24, 2006